

Yeonwoong Jung

List of Publications by Year in descending order

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papers

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61984

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times ranked

13765
citing authors

#	ARTICLE	IF	CITATIONS
1	Soft Biomorph Actuators Enabled by Wafer-Scale Ultrathin 2D PtTe ₂ Layers. <i>Advanced Materials Technologies</i> , 2022, 7, 2100639.	5.8	4
2	Revealing Pt-seed-induced structural effects to tribological/electrical/thermoelectric modulations in two-dimensional PtSe ₂ using scanning probe microscopy. <i>Nano Energy</i> , 2022, 91, 106693.	16.0	9
3	Atomic-scale characterization of structural heterogeneity in 2D TMD layers. <i>Materials Advances</i> , 2022, 3, 1401-1414.	5.4	5
4	MoS ₂ Synapses with Ultra-low Variability and Their Implementation in Boolean Logic. <i>ACS Nano</i> , 2022, 16, 2866-2876.	14.6	38
5	2D MoS ₂ -polyurethane sponge for solar-to-thermal energy conversion in environmental applications: Crude oil recovery and seawater desalination. <i>Journal of Water Process Engineering</i> , 2022, 47, 102665.	5.6	9
6	Peel-and-Stick Integration of Atomically Thin Nonlayered PtS Semiconductors for Multidimensionally Stretchable Electronic Devices. <i>ACS Applied Materials & Interfaces</i> , 2022, 14, 20268-20279.	8.0	5
7	Multiwavelength Optoelectronic Synapse with 2D Materials for Mixed-Color Pattern Recognition. <i>ACS Nano</i> , 2022, 16, 10188-10198.	14.6	47
8	Mechanically rollable photodetectors enabled by centimetre-scale 2D MoS ₂ layer/TOCN composites. <i>Nanoscale Advances</i> , 2021, 3, 3028-3034.	4.6	5
9	Multipurpose and Reusable Ultrathin Electronic Tattoos Based on PtSe ₂ and PtTe ₂ . <i>ACS Nano</i> , 2021, 15, 2800-2811.	14.6	46
10	Scalable Van der Waals Two-Dimensional PtTe ₂ Layers Integrated onto Silicon for Efficient Near-to-Mid Infrared Photodetection. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 15542-15550.	8.0	27
11	Cu-Ag Alloy Nanoparticles in Hydrogel Nanofibers for the Catalytic Reduction of Organic Compounds. <i>ACS Applied Nano Materials</i> , 2021, 4, 6045-6056.	5.0	21
12	Wafer-Scale Van der Waals Assembly of Free-Standing Near Atom Thickness Hetero-Membranes for Flexible Photo-Detectors. <i>Advanced Electronic Materials</i> , 2021, 7, 2100395.	5.1	4
13	A Case of Metastatic Uterine Tumor Originating from Small-Cell Lung Cancer (SCLC) Mimicking Uterine Sarcoma. <i>Case Reports in Obstetrics and Gynecology</i> , 2021, 2021, 1-4.	0.3	3
14	Layer Orientation-Engineered Two-Dimensional Platinum Ditelluride for High-Performance Direct Alcohol Fuel Cells. <i>ACS Energy Letters</i> , 2021, 6, 3481-3487.	17.4	12
15	A Library of Atomically Thin 2D Materials Featuring the Conductive-Point Resistive Switching Phenomenon. <i>Advanced Materials</i> , 2021, 33, e2007792.	21.0	67
16	Strain Effect in Palladium Nanostructures as Nanozymes. <i>Nano Letters</i> , 2020, 20, 272-277.	9.1	85
17	Superhydrophobic MoS ₂ -based multifunctional sponge for recovery and detection of spilled oil. <i>Current Applied Physics</i> , 2020, 20, 344-351.	2.4	16
18	Two-Dimensional Near-Atom-Thickness Materials for Emerging Neuromorphic Devices and Applications. <i>IScience</i> , 2020, 23, 101676.	4.1	44

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19	Large-area 2D PtTe ₂ /silicon vertical-junction devices with ultrafast and high-sensitivity photodetection and photovoltaic enhancement by integrating water droplets. <i>Nanoscale</i> , 2020, 12, 23116-23124.	5.6	20
20	Vertically Aligned 2D MoS ₂ Layers with Strain-Engineered Serpentine Patterns for High-Performance Stretchable Gas Sensors: Experimental and Theoretical Demonstration. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 53174-53183.	8.0	35
21	Artificial Nociceptor Using 2D MoS ₂ Threshold Switching Memristor. <i>IEEE Electron Device Letters</i> , 2020, 41, 1440-1443.	3.9	37
22	Controllable synthesis of platinum diselenide (PtSe ₂) inorganic fullerene. <i>Journal of Materials Chemistry A</i> , 2020, 8, 18925-18932.	10.3	12
23	Wafer-Scale Two-Dimensional MoS ₂ Layers Integrated on Cellulose Substrates Toward Environmentally Friendly Transient Electronic Devices. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 25200-25210.	8.0	31
24	Wafer-scale 2D PtTe ₂ layers-enabled Kirigami heaters with superior mechanical stretchability and electro-thermal responsiveness. <i>Applied Materials Today</i> , 2020, 20, 100718.	4.3	21
25	Investigating 2D WS ₂ supercapacitor electrode performance by Kelvin probe force microscopy. <i>Journal of Materials Chemistry A</i> , 2020, 8, 12699-12704.	10.3	29
26	Thickness-Independent Semiconducting-to-Metallic Conversion in Wafer-Scale Two-Dimensional PtSe ₂ Layers by Plasma-Driven Chalcogen Defect Engineering. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 14341-14351.	8.0	51
27	High-performance flexible asymmetric supercapacitor based on rGO anode and WO ₃ /WS ₂ core/shell nanowire cathode. <i>Nanotechnology</i> , 2020, 31, 435405.	2.6	29
28	Manufacturing strategies for wafer-scale two-dimensional transition metal dichalcogenide heterolayers. <i>Journal of Materials Research</i> , 2020, 35, 1350-1368.	2.6	12
29	Wafer-Scale Growth of 2D PtTe ₂ with Layer Orientation Tunable High Electrical Conductivity and Superior Hydrophobicity. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 10839-10851.	8.0	48
30	Automated Assembly of Wafer-Scale 2D TMD Heterostructures of Arbitrary Layer Orientation and Stacking Sequence Using Water Dissolvable Salt Substrates. <i>Nano Letters</i> , 2020, 20, 3925-3934.	9.1	25
31	2D MoS ₂ -Based Threshold Switching Memristor for Artificial Neuron. <i>IEEE Electron Device Letters</i> , 2020, 41, 936-939.	3.9	64
32	Wafer-scale 2D PtTe ₂ layers for high-efficiency mechanically flexible electro-thermal smart window applications. <i>Nanoscale</i> , 2020, 12, 10647-10655.	5.6	22
33	Large-area 2D TMD layers for mechanically reconfigurable electronic devices. <i>Journal Physics D: Applied Physics</i> , 2020, 53, 313002.	2.8	22
34	Two-Dimensional/Three-Dimensional Schottky Junction Photovoltaic Devices Realized by the Direct CVD Growth of vdW 2D PtSe ₂ Layers on Silicon. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 27251-27258.	8.0	46
35	Improving Electrochemical Pb ²⁺ Detection Using a Vertically Aligned 2D MoS ₂ Nanofilm. <i>Analytical Chemistry</i> , 2019, 91, 11770-11777.	6.5	73
36	Experimental Realization of Few Layer Two-Dimensional MoS ₂ Membranes of Near Atomic Thickness for High Efficiency Water Desalination. <i>Nano Letters</i> , 2019, 19, 5194-5204.	9.1	80

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37	Structural Evolutions of Vertically Aligned Two-Dimensional MoS ₂ Layers Revealed by in Situ Heating Transmission Electron Microscopy. <i>Journal of Physical Chemistry C</i> , 2019, 123, 27843-27853.	3.1	13
38	Supercluster-Coupled Crystal Growth in Metallic Glass Forming Liquids. <i>Microscopy and Microanalysis</i> , 2019, 25, 1410-1411.	0.4	0
39	Electronic synapses with near-linear weight update using MoS ₂ /graphene memristors. <i>Applied Physics Letters</i> , 2019, 115, .	3.3	52
40	Multifunctional Two-Dimensional PtSe ₂ -Layer Kirigami Conductors with 2000% Stretchability and Metallic-to-Semiconducting Tunability. <i>Nano Letters</i> , 2019, 19, 7598-7607.	9.1	59
41	Horizontal-to-Vertical Transition of 2D Layer Orientation in Low-Temperature Chemical Vapor Deposition-Grown PtSe ₂ and Its Influences on Electrical Properties and Device Applications. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 13598-13607.	8.0	77
42	Recent trends in transition metal dichalcogenide based supercapacitor electrodes. <i>Nanoscale Horizons</i> , 2019, 4, 840-858.	8.0	207
43	Supercluster-coupled crystal growth in metallic glass forming liquids. <i>Nature Communications</i> , 2019, 10, 915.	12.8	30
44	Novel mesoporous electrode materials for symmetric, asymmetric and hybrid supercapacitors. <i>Nanotechnology</i> , 2019, 30, 202001.	2.6	75
45	Centimeter-scale Green Integration of Layer-by-Layer 2D TMD vdW Heterostructures on Arbitrary Substrates by Water-Assisted Layer Transfer. <i>Scientific Reports</i> , 2019, 9, 1641.	3.3	44
46	A leaf-inspired photon management scheme using optically tuned bilayer nanoparticles for ultra-thin and highly efficient photovoltaic devices. <i>Nano Energy</i> , 2019, 58, 47-56.	16.0	86
47	Artificial Neuron using Vertical MoS ₂ /Graphene Threshold Switching Memristors. <i>Scientific Reports</i> , 2019, 9, 53.	3.3	69
48	Two-dimensional transition metal dichalcogenide hybrid materials for energy applications. <i>Nano Today</i> , 2018, 19, 16-40.	11.9	142
49	Recent Advances in Two-Dimensional Nanomaterials for Supercapacitor Electrode Applications. <i>ACS Energy Letters</i> , 2018, 3, 482-495.	17.4	618
50	Uniform Vapor-Pressure-Based Chemical Vapor Deposition Growth of MoS ₂ Using MoO ₃ Thin Film as a Precursor for Coevaporation. <i>ACS Omega</i> , 2018, 3, 18943-18949.	3.5	30
51	Strain-Driven and Layer-Number-Dependent Crossover of Growth Mode in van der Waals Heterostructures: 2D/2D Layer-by-Layer Horizontal Epitaxy to 2D/3D Vertical Reorientation. <i>Advanced Materials Interfaces</i> , 2018, 5, 1800382.	3.7	35
52	Extraordinary Enhancement of UV Absorption in TiO ₂ Nanoparticles Enabled by Low-Oxidized Graphene Nanodots. <i>Journal of Physical Chemistry C</i> , 2018, 122, 12114-12121.	3.1	30
53	Centimeter-Scale Periodically Corrugated Few-Layer 2D MoS ₂ with Tensile Stretch-Driven Tunable Multifunctionalities. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 30623-30630.	8.0	21
54	Three dimensionally-ordered 2D MoS ₂ vertical layers integrated on flexible substrates with stretch-tunable functionality and improved sensing capability. <i>Nanoscale</i> , 2018, 10, 17525-17533.	5.6	31

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55	Asymmetric Supercapacitor Electrodes and Devices. <i>Advanced Materials</i> , 2017, 29, 1605336.	21.0	1,021
56	Supercapacitors: Asymmetric Supercapacitor Electrodes and Devices (<i>Adv. Mater.</i> 21/2017). <i>Advanced Materials</i> , 2017, 29, .	21.0	2
57	Noble metal-coated MoS ₂ nanofilms with vertically-aligned 2D layers for visible light-driven photocatalytic degradation of emerging water contaminants. <i>Scientific Reports</i> , 2017, 7, 14944.	3.3	51
58	Centimeter-Scale 2D van der Waals Vertical Heterostructures Integrated on Deformable Substrates Enabled by Gold Sacrificial Layer-Assisted Growth. <i>Nano Letters</i> , 2017, 17, 6157-6165.	9.1	28
59	Tailoring crystallization phases in metallic glass nanorods via nucleus starvation. <i>Nature Communications</i> , 2017, 8, 1980.	12.8	31
60	Charge Transfer from Carbon Nanotubes to Silicon in Flexible Carbon Nanotube/Silicon Solar Cells. <i>Small</i> , 2017, 13, 1702387.	10.0	18
61	Strength dependence of epoxy composites on the average filler size of non-oxidized graphene flake. <i>Carbon</i> , 2017, 113, 379-386.	10.3	63
62	Two-dimensional lateral heterojunction through bandgap engineering of MoS ₂ via oxygen plasma. <i>Journal of Physics Condensed Matter</i> , 2016, 28, 364002.	1.8	47
63	High-Performance One-Body Core/Shell Nanowire Supercapacitor Enabled by Conformal Growth of Capacitive 2D WS ₂ Layers. <i>ACS Nano</i> , 2016, 10, 10726-10735.	14.6	209
64	Centimeter Scale Patterned Growth of Vertically Stacked Few Layer Only 2D MoS ₂ /WS ₂ van der Waals Heterostructure. <i>Scientific Reports</i> , 2016, 6, 25456.	3.3	116
65	Intercalation in two-dimensional transition metal chalcogenides. <i>Inorganic Chemistry Frontiers</i> , 2016, 3, 452-463.	6.0	181
66	One-Step Synthesis of MoS ₂ /WS ₂ Layered Heterostructures and Catalytic Activity of Defective Transition Metal Dichalcogenide Films. <i>ACS Nano</i> , 2016, 10, 2004-2009.	14.6	164
67	Recent Advances in Two-Dimensional Materials beyond Graphene. <i>ACS Nano</i> , 2015, 9, 11509-11539.	14.6	2,069
68	Nanoscale size effects in crystallization of metallic glass nanorods. <i>Nature Communications</i> , 2015, 6, 8157.	12.8	65
69	Metal Seed Layer Thickness-Induced Transition From Vertical to Horizontal Growth of MoS ₂ and WS ₂ . <i>Nano Letters</i> , 2014, 14, 6842-6849.	9.1	251
70	Chemically Synthesized Heterostructures of Two-Dimensional Molybdenum/Tungsten-Based Dichalcogenides with Vertically Aligned Layers. <i>ACS Nano</i> , 2014, 8, 9550-9557.	14.6	70
71	Surface effects on electronic transport of 2D chalcogenide thin films and nanostructures. <i>Nano Convergence</i> , 2014, 1, 18.	12.1	24
72	Synthesis of SnTe Nanoplates with {100} and {111} Surfaces. <i>Nano Letters</i> , 2014, 14, 4183-4188.	9.1	75

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73	Device Area Scale-Up and Improvement of SWNT/Si Solar Cells Using Silver Nanowires. <i>Advanced Energy Materials</i> , 2014, 4, 1400186.	19.5	35
74	Record High Efficiency Single-Walled Carbon Nanotube/Silicon p-n Junction Solar Cells. <i>Nano Letters</i> , 2013, 13, 95-99.	9.1	193
75	Improved efficiency of smooth and aligned single walled carbon nanotube/silicon hybrid solar cells. <i>Energy and Environmental Science</i> , 2013, 6, 879.	30.8	87
76	Silicon nanowires: electron holography studies of doped p-n junctions and biased Schottky barriers. <i>Nanotechnology</i> , 2013, 24, 115703.	2.6	27
77	Electrical Wind Force-Driven and Dislocation-Templated Amorphization in Phase-Change Nanowires. <i>Science</i> , 2012, 336, 1561-1566.	12.6	162
78	Mapping of near field light and fabrication of complex nanopatterns by diffraction lithography. <i>Nanotechnology</i> , 2012, 23, 045301.	2.6	7
79	High-Resolution Transmission Electron Microscopy Study of Electrically-Driven Reversible Phase Change in $\text{Ge}_2\text{Sb}_2\text{Te}_5$ Nanowires. <i>Nano Letters</i> , 2011, 11, 1364-1368.	9.1	58
80	Minority Carrier Lifetimes and Surface Effects in VLS-Grown Axial p-n Junction Silicon Nanowires. <i>Advanced Materials</i> , 2011, 23, 4306-4311.	21.0	32
81	Chalcogenide phase-change memory nanotubes for lower writing current operation. <i>Nanotechnology</i> , 2011, 22, 254012.	2.6	18
82	Extremely low drift of resistance and threshold voltage in amorphous phase change nanowire devices. <i>Applied Physics Letters</i> , 2010, 96, .	3.3	91
83	Nanowire Transformation by Size-Dependent Cation Exchange Reactions. <i>Nano Letters</i> , 2010, 10, 149-155.	9.1	74
84	Electromechanical properties of individual single-walled carbon nanotubes grown on focused-ion-beam patterned substrates. <i>Ultramicroscopy</i> , 2009, 109, 167-171.	1.9	2
85	Diameter-Controlled Synthesis of Phase-Change Germanium Telluride Nanowires via the Vapor-Liquid-Solid Mechanism. <i>Journal of Physical Chemistry C</i> , 2009, 113, 6898-6901.	3.1	25
86	Phase-Change Ge_2Sb Nanowires: Synthesis, Memory Switching, and Phase-Instability. <i>Nano Letters</i> , 2009, 9, 2103-2108.	9.1	37
87	Epitaxial Growth and Ordering of GeTe Nanowires on Microcrystals Determined by Surface Energy Minimization. <i>Nano Letters</i> , 2009, 9, 2395-2401.	9.1	28
88	Comparative study of memory-switching phenomena in phase change GeTe and $\text{Ge}_2\text{Sb}_2\text{Te}_5$ nanowire devices. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2008, 40, 2474-2480.	2.7	36
89	Core-Shell Heterostructured Phase Change Nanowire Multistate Memory. <i>Nano Letters</i> , 2008, 8, 2056-2062.	9.1	103
90	A Generic Approach for Embedded Catalyst-Supported Vertically Aligned Nanowire Growth. <i>Nano Letters</i> , 2008, 8, 1328-1334.	9.1	20

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91	Size-Dependent Surface-Induced Heterogeneous Nucleation Driven Phase-Change in Ge ₂ Sb ₂ Te ₅ Nanowires. Nano Letters, 2008, 8, 3303-3309.	9.1	72
92	Synthesis and Structural Characterization of Single-Crystalline Branched Nanowire Heterostructures. Nano Letters, 2007, 7, 264-268.	9.1	165
93	Nanoscopically Flat Open-Ended Single-Walled Carbon Nanotube Substrates for Continued Growth. Nano Letters, 2007, 7, 15-21.	9.1	10
94	Highly scalable non-volatile and ultra-low-power phase-change nanowire memory. Nature Nanotechnology, 2007, 2, 626-630.	31.5	389
95	Size-dependent phase transition memory switching behavior and low writing currents in GeTe nanowires. Applied Physics Letters, 2006, 89, 223116.	3.3	116
96	Synthesis and Characterization of Ge ₂ Sb ₂ Te ₅ Nanowires with Memory Switching Effect. Journal of the American Chemical Society, 2006, 128, 14026-14027.	13.7	111